



**Product Specification** 

TUDI-SN65ALS180/SN75ALS180

Low power RS-485 line driver and receiver pair

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### 用芯智造・卓越品质

semiconductor device manufacturer

- Design
- research and development
- production
- and sales





#### **Features**

- Complies with or exceeds requirements of TIA/EIA-422
   TIA/EIA-485
- High-speed advanced low-power Schottky circuitry
- Designed for 25Mbaud operation in both serial and parallel applications
- Low device--device delay: 6ns (max)
- Low power supply current requirement: 30 mA (max)
- Independent drivers and receivers with separate I/ pins for dual VCC and dual GND
- Wide ±input/output bus voltage range
- Driver output capability: ±60mA
- Driver current limiting
- iver input impedance: 12k minimum
- Receiver input sensitivity: ±200mV (max)
- Receiver input hysteresis: 6 mV (typ)
- Operates from a single 5V power supply

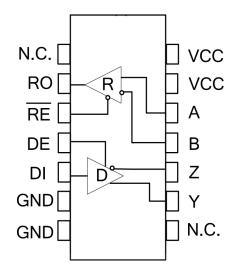


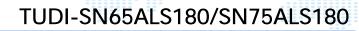
Figure 1 Pin diagram

### Description

The SN65ALS180 and SN75ALS180 differential driver and receiver pairs are integrated circuits designed for bidirectional data on multipoint bus transmission lines. These devices are designed for balanced transmission lines and comply with TIA/EIA-422, TIA/EIA-485.

The SN65ALS180 and SN75ALS180 integrate a three-state differential line driver and a differential input line receiver, both powered by single 5V supply. The driver and receiver have separate high-level and low-level active enable inputs, which can be connected together externally to function as direction control. The differential outputs and the receiver differential inputs are connected to separate termination to achieve greater flexibility, and these ports are used to provide a minimum load to the bus when the driver is disabled or CC = 0.

These ports have a positive and negative wide common mode voltage range, making the device well suited for common mode applications





# Pin description

Pin number	Pin name	Pin function
1	NC	No internal connections required
2	RO	Receiver output.When RE is low,the RO output is high if A-B is -10mV,and low if A-B is -200mV.
3	/RE	Receiver output enable control.When/RE is low,the receiver output is enabled and RO is active;when/REis high,the receiver output is disabled and RO is in high-impedance state.When RE is at a high level and DE is at a low level,the device enters low-power shutdown mode
4	DE	The driver output enables the control. When DE is at high level, the driver outputs effectively; when DE is low, it outputs high-impedance state. When RE is high and DE is low, the device enters low-power shutdown mode.
5	DI	DI driver input.When DE is high, the low level on DI makes the in-phase output A of the driver low and the in-phase output B high; the high levelon DI makes the in-phase output high and the in-phase output Blow.
6	GND	Landing
7	GND	Landing
8	NC	No internal connections required
9	Υ	Driver in-phase output terminal
10	Z	Driver inverting output
11	В	Receiver inverting input
12	А	Receiver in phase input
13	VCC	This pin can be connected to power or left unconnec-ted
14	VCC	Power connection



### Extreme parameter

Parameter	Symbol	Unit	size
Continuous nower consumption	SOP14	mW	600
Continuous power consumption	DIP14	mW	700
Power supply voltage	VCC	V	+7
working temperature range			-40~125
Storage temperature range		- \   2	-60~150
Welding temperature range			300
Control port voltage	DI	V	-0.3~VCC+0.3
Bus side input voltage	A, B	V	-8~13
Receiver output voltage	RO	V	-0.3~VCC+0.3

The maximum limit parameters are values beyond which the device can be damaged in an irreversible manner. Operation of the device under these conditions is not intended to be normal and may affect the reliability of the device if operated continuously at the maximum rated limit. All voltages are referenced to ground.

ESD Protect								
Parameter	symbol	Test condition	Minimum	Typical case	Maximum	Unit		
A、B、Y、Z		Human bodymodel		±15		KV		
Other ports		Human bodymodel		±6		KV		



Receiver Switching Characteris-tics								
Parameter	symbol	Test condition	Minimum	Typical case	Maximum	Unit		
Acceptor	tRPLH	See Figure 7 and Figure 8	20	60	90	ns		
Input to output propag- ation delay from low to high								
The propagation delay from receiverinput to output is from high to low	tRPHL	V 2.0V;risingand falling edgetime ViD 15ns	20	60	90	ns		
tRPLH-tRPHLI	tsKEW2			7	10	ns		
Enable low time out	tRPZL	CL=15pF SeeFigures 7 and 8		20	50	ns		
Enable to output high time	tRPZH	CL=15pF SeeFigures 7 and 8		20	50	ns		
Time from output low to disable	tpRLZ	CL=15pF SeeFigures 7 and 8	10011	20	45	ns		
Time from output high to disable	tpRHZ	CL=15pF SeeFigures 7 and 8		20	45	ns		
Off stateEnable to output high time	tRPSH	CL=15pF SeeFigures 7 and 8		200	1400	ns		
Off stateEnable low time out	tRPSL	CL=15pF SeeFigures 7 and 8		200	1400	ns		
Time to turn off	tsHDN	NOTE2	80		300	ns		

(If not otherwise, VCC= $3V\sim5.5V$ , Temp = TMIN  $\sim$  TMAX, typical value at Temp = 25) NOTE 1:? VO D and? VOC is the change in VOD and VOC amplitude caused when the DI state of the input signal changes, respectively.



DC electrical characteristics of thedriver								
Parameter	symbol	Test condition	Minimum	Typical case	Maximum	Unit		
Driver differential output (non-loaded)	VoD <sub>1</sub>			4.5	VCC	V		
Drive differential output	VoD <sub>2</sub>	graph 2,RL=27	1.5	2.3	VCC	V		
Drive differential output	VOD2	graph 2,RL=50	2	2.8	VCC	V		
Variation in the amplitude of the output voltage (NOTE1)	VoD	graph 2,RL=27			0.2	V		
Output common mode voltage	Voc	graph 2,RL=27	7 \	/ E	3			
Amplitude Variation of Common Mode Output Voltage(NOTE1)	Voc	graph 2,RL=27			0.2	V		
High-level input	VH	DI DI	2.0	lauc	tol	V		
Low level input	V	DI			0.8	V		
Logic input current	IN1	DI	-2		2	uA		
Output the current during ashort circuit, with high short-circuit	losD <sub>1</sub>	Short circuit to OV~12V	35		250	mA		
Output the current during ashort circuit,down to low	losD <sub>2</sub>	Short circuit to- 7V~0V	-250		-35	mA		

(If not otherwise, VCC= $3V\sim5.5V$ , Temp = TMIN  $\sim$  TMAX, typical value at Temp = 25) NOTE 1:? VO D and? VOC is the change in VOD and VOC amplitude caused when the DI state of the input signal changes, respectively.



drive switch characteristics								
Parameter	symbol	Test condition	Minimum	Typical case	Maximum	Unit		
Input to output propagation delay (low to high)	tDPLH			12	35	ns		
Input to output propagation delay (high to low)	tDPHL	RDIFF=54 ,CL= CL?=100pF(see		12	35	ns		
tDPLH-tDPHLI	tsKEW1	Fi-gure 3 and Figure 4)		6	10	ns		
Rise time /fall time	tDR,tDF			9	25	ns		
Enable to high output	tpZH	R=110 (seeFigure 5 and 6)		20	90	ns		
Enable to output low	tpZL	<b>-</b>		20	90	ns		
Input low to disable	tpLZ	R=110 (seeFigure 5 and 6)		20	80	ns		
Enable high input	tpHZ	ıdi Sen	nicor	20	80	ns		
Enable high outputunder off condition	tDSH	R=110 (seeFigure 5 and 6)		500	900	ns		
Enable low outputunder shutdown conditions	tDSL	RL=110 (seeFigure 5 and 6)		500	900	ns		

Supply Current									
Parameter	symbol	Test condition	Minimum	Typicel case	Maximum	Unit			
	Iccl	/RE=0V,DE=0V		220	400	uA			
Supply current	Icc2	/RE=VCC, DE=VCC		240	400	uA			
Turn-off current	IsHDN	/RE=VCC,DE=0V		0.5	10	uA			



#### DC Electrical Characteristics of the Receiver

			•			
Parameter	symbol	Test condition	Minimum	Typical case	Maximum	Unit
Input ourront(A.D.)	IN2	VCC=0 or 3.3V VIn=12V			125	uA
Input current(A,B)	IINZ	VCC=0 or 3.3V VIn=-7V	-100			uA
Forward input threshold voltage	VIT+	-7V Vcm 12V			-10	mV
Reverse input threshold voltage	VIT-	-7V Vcm 12V	-200			mV
Input hysteresis voltage	Vhys	-7V Vcm 12V	10	30	=-	mV
High level output voltage	VoH	IoUT=-4mA, VID=+200 mV	VCC-1.5	ndu	ctor	V
Low level output voltage	VoL	IoUT=+4mA, VID=-200 mV			0.4	V
Three state input leakage cur-rent	lozR	0.4V <vo<2.4v< td=""><td></td><td></td><td>±1</td><td>uA</td></vo<2.4v<>			±1	uA
Input resistance of receiver	RIN	-7V VcM 12V	96			k
Receiver short circuit curr-ent	IosR	0V Vo VCC	±7		±95	mA

### **Function table**

Receiving function table							
cor	itrol	input	output				
/RE	DE	A-B	RO				
0	x	≥-10mV	Н				
0	х	≤-200mV	L				
0	Х	Open/short circuit	Н				
1	Х	Х	Z				

X: any	level;	Z: ł	nigh	impedance.
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Send function table							
cont	control		output				
/RE	DE	DI	Y	Z			
х	1	1	н	L			
х	1	0	L	н			
0	0	х	Z	Z			
1	0	Х	Z(shutdown)				

X: any level; Z: high impedance.

# Additional description Tudi Semiconductor

#### Introduction

The ALS180 is a full-duplex high-speed transceiver for RS-485/RS-42 communication, containing a driver and a receiver. It has fail-safe, overvoltage protection, and overcurrent protection. The ALS180 achieves error-free transmission up to 12Mbps.

#### fail-safe

The ALS180 guarantees a logic high receiver output if the receiver input is short-circuited or open-circuited,or drivers connected to the terminated transmission line are disabled (idle). This is achieved by setting the receiver input thresholds to -10mV and -20mV, respectively. RO is logic high if the differential receiver input voltage(A-B)≥-10mV, and RO is logic low the voltage(A-B)≤-200mV. Logic high with a minimum noise margin of 50mV can be realized depending the receiver thresholds. The-10mV to -200mV threshold voltage is in accordance with the EIA/TIA-485 of±200mV.

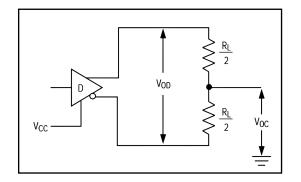
#### 256 transceivers on the bus

The input impedance of the standard RS485 receiver is 12k (1 unit load), and the standard driver can drive to 32 unit loads. The receiver of the ALS180 transceiver has an input impedance of 1/8 unit load (96k allowing up to 256 transceivers to be connected in parallel on the same communication bus. These devices can be combined arbitrarily, or combined with other 485 transceivers, as long as the total load does not exceed 256 unit loads, they can be connected to the same bus.

#### Drive output protection

Protection against excessive output current and dissipation by fault or bus contention is provided by overcurrent and overvoltage protection mechanisms, with fast short-circuit throughout the common-mode voltage range(see Typical Operating Characteristics).

### Test circuit



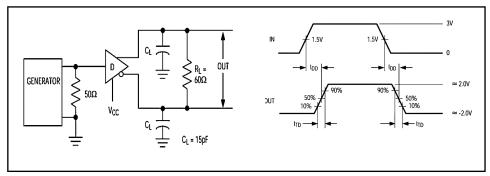


Figure 2: DC test load for the drive

Figure 3 Drive-line Differential Delay and Transit Time

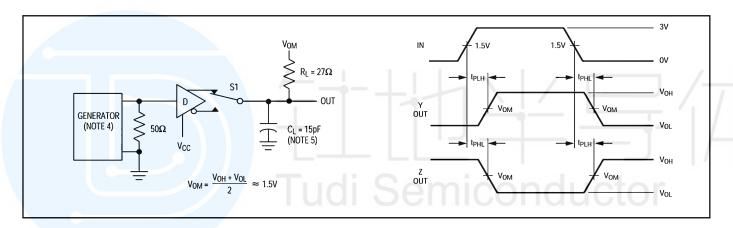


Figure 4 Drive propagation delay

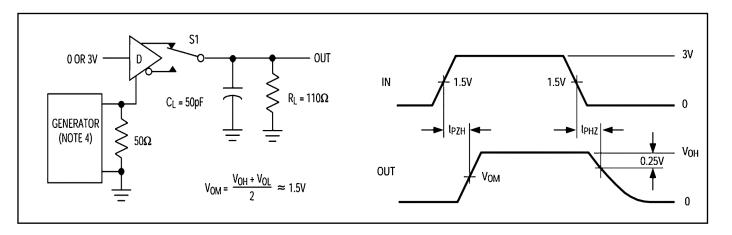


Figure 5 Drive enable and disable time



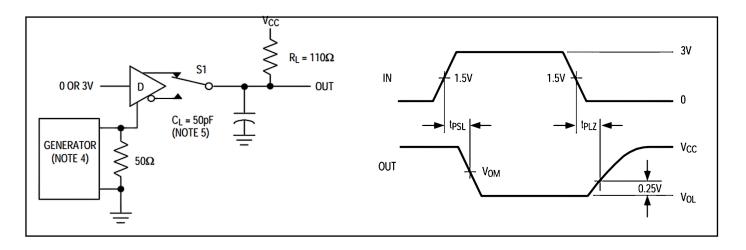


Figure 6 Drive enable and disable time

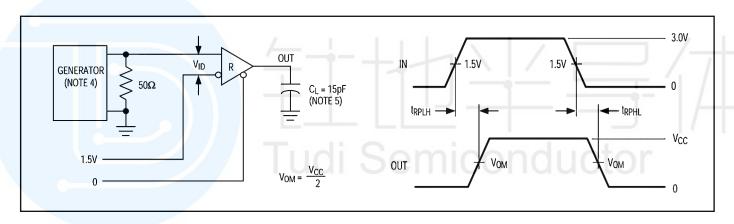
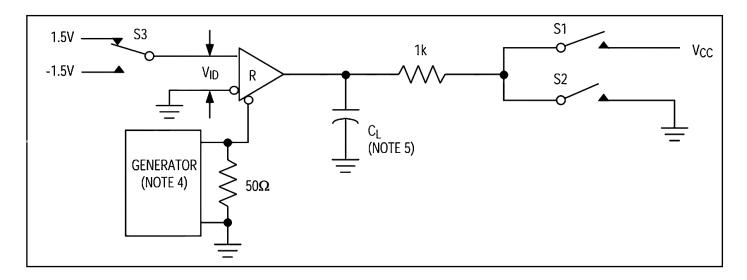


Figure 7: Receiver Propagation Delay Test Circuit





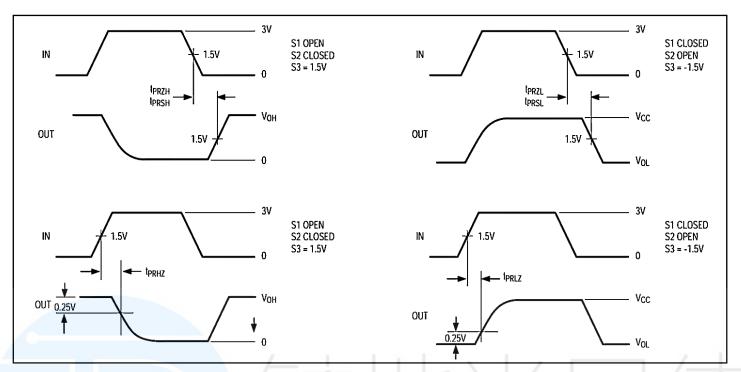


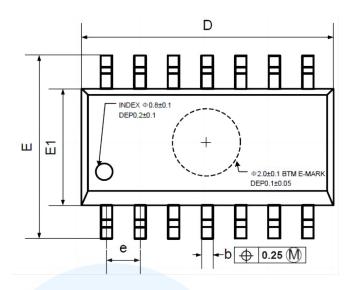
Figure 8 Receive enable and disable time

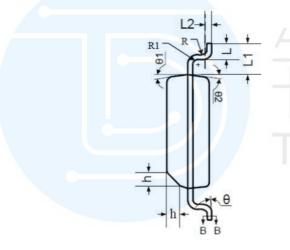
### Order information

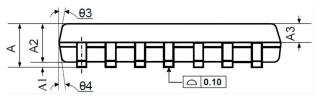
Order Number	Package	Package Quantity Marking On The park		Temperature
SN75ALS180N-TUDI	DIP14	Tube,25,A box of 1000	SN75ALS180N	0°C to 70°C
SN75ALS180DR-TUDI	SOP14	Tape,Reel,2500	75ALS180	0000700
SN65ALS180N-TUDI	DIP14	Tube,25,A box of 1000	SN65ALS180N	- 40°C to 85°C
SN65ALS180DR-TUDI	SOP14	Tape,Reel,2500	65ALS180	- 40 C 10 65 C

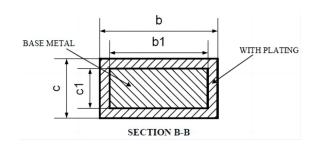


# Package SOP14







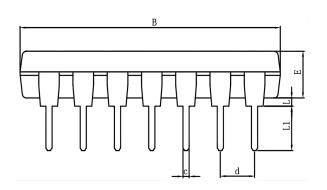


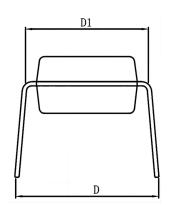
Symbol	Dimensions In Millimeters					
Symbol	MIN NOM		MAX			
А	1.35	1.60	1.75			
A1	0.10	0.15	0.25			
A2	1.25	1.45	1.65			
А3	0.55	0.65	0.75			
b	0.36		0.49			
b1	0.35	0.40	0.45			
С	0.16		0.25			
c1	0.15	0.20	0.25			
D	8.53	8.63	8.73			
E	5.80	6.00	6.20			
E1	3.80	3.90	4.00			
е	1.27 BSC					
L	0.45	0.60	0.80			
L1	1.04 REF					
L2	0.25 BSC					
R	0.07					
R1	0.07					
h	0.30	0.40	0.50			
θ	0°		8°			
θ1	6°	8°	10°			
θ2	6°	8°	10°			
θ3	5°	7°	9°			
θ4	5°	7°	9°			

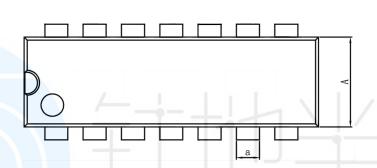




# Package DIP14







DIM.	MIN	ТҮР	MAX	DIM.	MIN	ТҮР	MAX
А	6.100	6.300	6.680	а	1.504	1.524	1.544
В	18.940	19.200	19.560	C	0.437	0.457	0.477
D	8.200	8.700	9.200	d	2.530	2.540	2.550
D1	7.42	7.62	7.82	L	0.500	_	0.800
E	3.100	3.300	3.550	L1	3.000	3.200	3.600



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